

1N5391 THRU 1N5399

1.5 AMP.Plastic silicon Rectifier

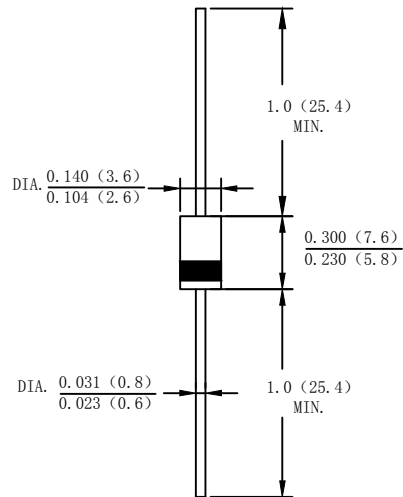
Features

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability

Mechanical Data

- Case: Moeded plastic DO-15
- Terminals: Axial leads solderable to MIL-STD-202,Method 208
- Polarity: Color band dentes cathode end
- Mounting Position: Any

DO-15



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load

For capacitive load derate current by 20%

Type Number	SYMBOL	1N5391	1N5392	1N5393	1N5394	1N5395	1N5396	1N5397	1N5398	1N5399	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RM}	50	100	200	300	400	500	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	350	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	500	600	800	1000	V
Average Rectified Output Current (Note 1) @ $T_A=60^\circ C$	I_o	1.5									A
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50									A
Forward Voltage @ $I_F=1.5A$	V_{FM}	1.1									V
Peak Reverse Current @ $T_A=25^\circ C$	I_R	5.0									uA
At Rated DC Blocking Voltage @ $T_A=100^\circ C$		100									
Typical Junction Capacitance (Note 2)	C_j	20									pF
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	26									K/W
Operating Temperature Range	T_j	-55 to +125									°C
Storage Temperature Range	T_{STG}	-55 to +150									°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied reverse Voltage of 4.0V D.C

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FIG. 1 – FORWARD CURRENT DERATING CURVE

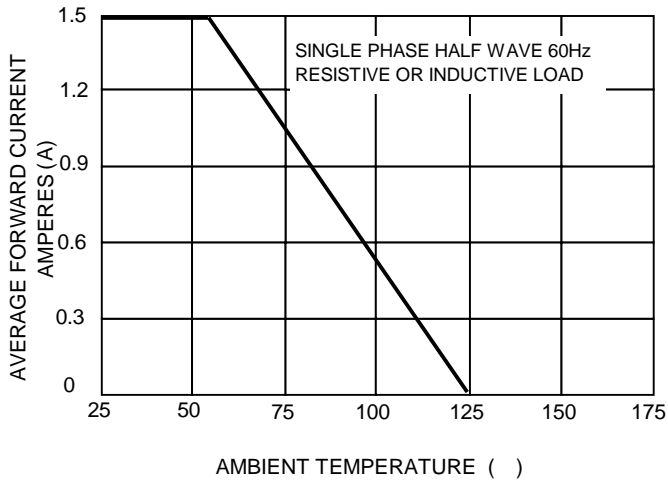


FIG.2-TYPICAL FORWARD CHARACTERISTICS

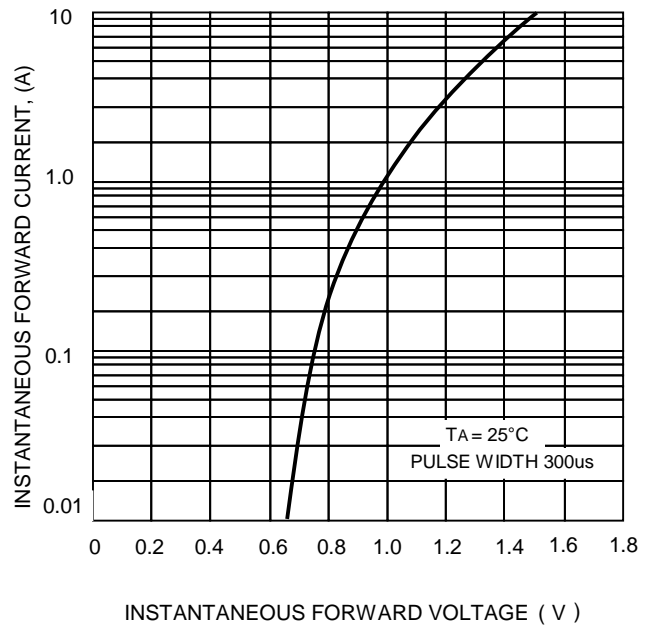


FIG. 3 – MAXIMUM NON-REPETITIVE SURGE CURRENT

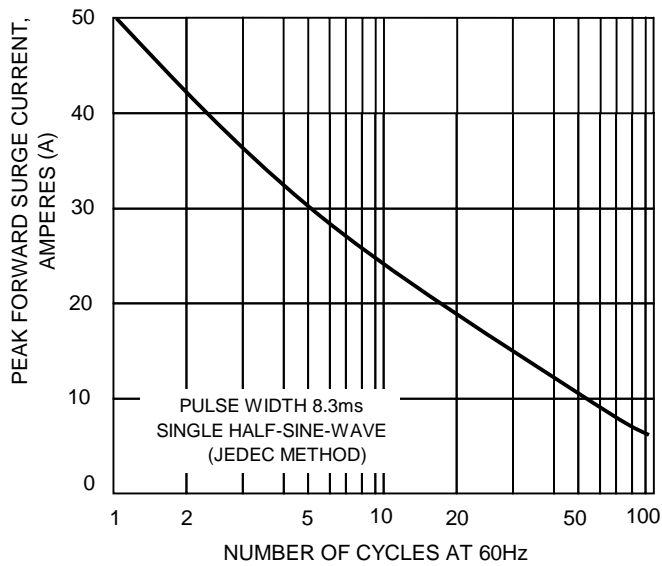


FIG.4 – TYPICAL JUNCTION CAPACITANCE

